## NSN 5961-01-035-5813

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-035-5813 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Overall Height:** Between 0.125 inches and 0.165 inches Overall Width: Between 0.175 inches and 0.205 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 750.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 135.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6045 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**